NSN 5962-01-385-8906

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and electrostatic sensitive and monolithic and programmed

Inclosure Configuration:

Dual-in-line

Case Outline Source And Designator:

D-8 mil-m-38510

Product Name:

16-input 8-output and-or invert gate array

Voltage Rating And Type Per Characteristic:

-0.5 volts absolute input and 5.5 volts absolute input

Memory Device Type:

Pal

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Departure From Cited Designator:

Programmed per: 7358047-00

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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